

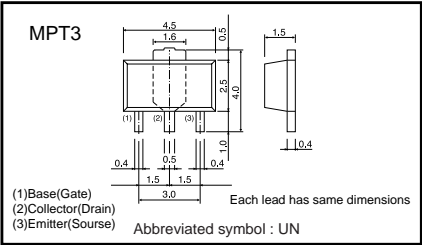
Power transistor (−60V, −3A)

2SA2071

●Features

- 1) High speed switching. (Tf : Typ. : 20ns at Ic = −3A)
- 2) Low saturation voltage, typically
(Typ. : −200mV at Ic = −2A, Ib = −0.2A)
- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SC5824

●Dimensions (Unit : mm)



●Applications

Low Frequency Amplifier
High speed switching

●Structure

PNP Silicon epitaxial planar transistor

●Packaging specifications

Type	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SA2071		○

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CBO}	−60	V
Collector-emitter voltage	V _{CEO}	−60	V
Emitter-base voltage	V _{EBO}	−6	V
Collector current	I _C	−3	A
	I _{CP}	−6	A *1
Power dissipation	P _C	500	mW
		2.0	W *2
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	−55~+150	°C

*1 Pw=100ms

*2 Mounted on a 40×40×0.7 (mm) ceramic substrate

Transistor

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CB0}	-60	-	-	V	I _C =-100μA
Collector-emitter breakdown voltage	BV _{CE0}	-60	-	-	V	I _C =-1mA
Emitter-base breakdown voltage	BV _{EB0}	-6	-	-	V	I _E =-100μA
Collector cut-off current	I _{CB0}	-	-	-1.0	μA	V _{CB} =-40V
Emitter cut-off current	I _{EB0}	-	-	-1.0	μA	V _{EB} =-4V
Collector-emitter saturation voltage	V _{CE(sat)}	-	-200	-500	mV	I _C =-2A, I _B =-0.2A *1
DC current gain	h _{FE}	120	-	390	-	V _{CE} =-2V, I _C =-100mA
Transition frequency	f _T	-	180	-	MHz	V _{CE} =-10V, I _E =10mA, f=10MHz *1
Collector output capacitance	C _{ob}	-	50	-	pF	V _{CB} =-10V, I _E =0mA, f=1MHz
Turn-on time	T _{on}	-	20	-	ns	I _C =-3A I _{B1} =-300mA
Storage time	T _{stg}	-	150	-	ns	I _{B2} =300mA
Fall time	T _f	-	20	-	ns	V _{CC} =-25V *2

*1 Non repetitive pulse

*2 See switching characteristics measurement circuits

●h_{FE} RANK

Q
120-270

●Electrical characteristic curves

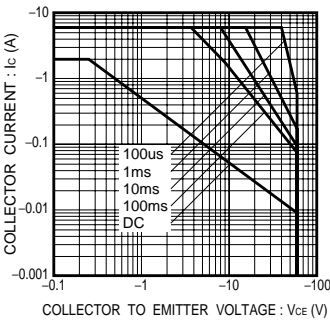


Fig.1 Safe Operating Area

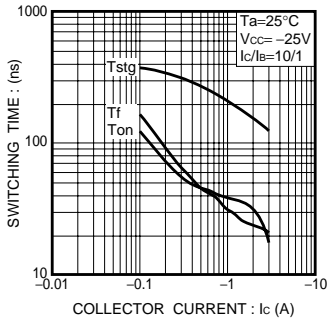


Fig.2 Switching Time

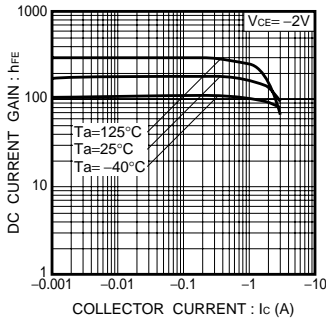


Fig.3 DC Current Gain vs. Collector Current (I)

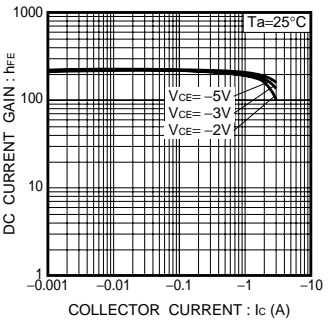


Fig.4 DC Current Gain vs. Collector Current (II)

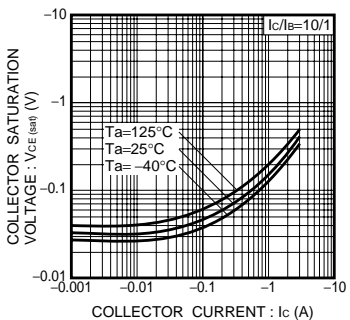


Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)

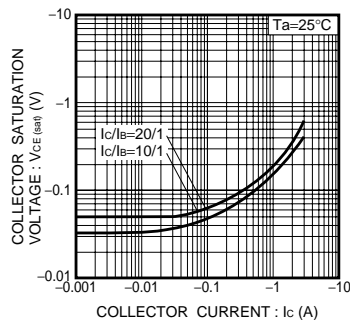


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)

Transistor

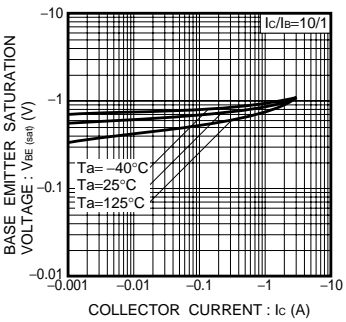


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

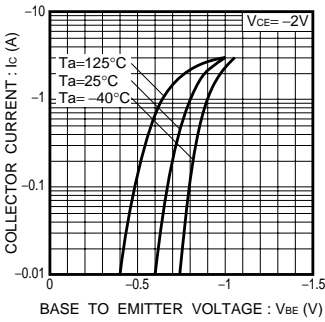


Fig.8 Grounded Emitter Propagation Characteristics

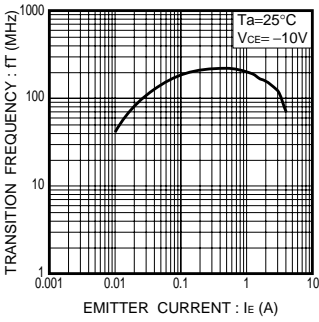


Fig.9 Transition Frequency

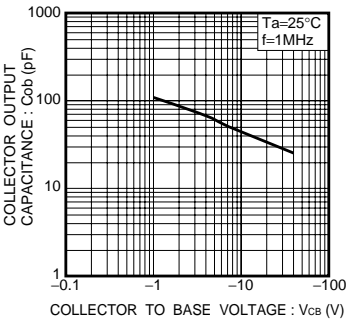
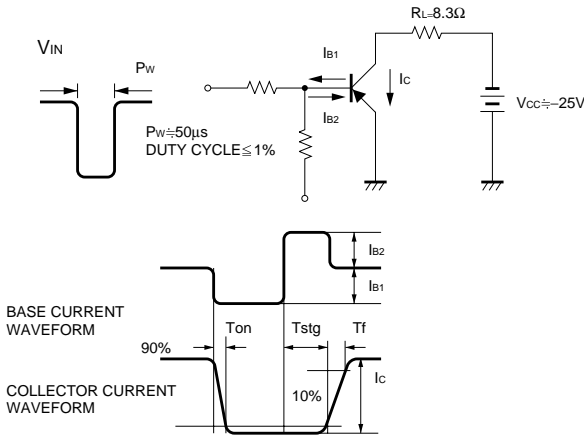


Fig.10 Collector Output Capacitance

●Switching characteristics measurement circuits



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